

Is the application of T. OSABE et al

Serial No.: 09/944,073

Filed: September 4, 2001

Group Art Unit: 2826

Examiner: T. Tran

For: A SEMICONDUCTOR NON-VOLATILE MEMORY (As Amended)

Assistant Commissioner for Patents  
Washington, D.C. 20231

Sir:

Transmitted herewith is an Amendment in the above-identified application.

- ☐ Small entity status of this application under 37 CFR 1.9 and 1.27 has been established by a verified statement previously submitted.
- ☐ A verified statement to establish small entity status under 37 CFR 1.9 and 1.27 is enclosed.
- ☒ No additional fee is required.

The fee has been calculated as shown below:

	(COL. 1)		(COL. 2)		(COL. 3)
	Claims Remaining After Amendment		Highest No. Previously Paid For		Present Extra
Total	* 4	Minus	** 12	=	0
Indep.	* 4	Minus	*** 8	=	0
<input type="checkbox"/> First Presentation of Multiple Dependent Claims					

SMALL ENTITY	
Rate	Additional Fee
x 9	\$
x 42	\$
+ 140	\$
Total	\$

OR

OTHER THAN A SMALL ENTITY	
Rate	Additional Fee
x 18	\$ 0
x 84	\$ 0
+ 280	\$ 0
Total	\$ 0

OR

- \* If the entry in Col. 1 is less than the entry in Col. 2, write '0' in Col. 3.
- \*\* If the 'Highest Number Previously Paid For' IN THIS SPACE is less than 20, write '20' in this space.
- \*\*\* If the 'Highest Number Previously Paid For' IN THIS SPACE is less than 3, write '3' in this space.
- The 'Highest Number Previously Paid For' (Total or Independent) is the highest number found from the equivalent box in Col. 1 of a prior Amendment or the number of claims originally filed.

☐ Please charge my Deposit Account No. 50-1417 in the amount of \$ \_\_\_\_\_.

☐ A check in the amount of \$ \_\_\_\_\_ is attached in payment of:

☒ The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. 50-1417.

- ☒ Any filing fees under 37 CFR 1.16 for the presentation of extra claims.
- ☒ Any patent application processing fees under 37 CFR 1.17.
- ☒ Any Extension of Time fees that are necessary, which are hereby requested if necessary.

MATTINGLY, STANGER & MALUR, P.C.  
1800 Diagonal Rd., Suite 370  
Alexandria, Virginia 22314  
(703) 684-1120

Date: March 6, 2003

By:

*[Signature]*  
Shrinath Malur  
Registration No. 34,663  
Attorney for Applicant(s)

RECEIVED  
MAR - 7 2003  
TECHNOLOGY CENTER 2800



NIT-304

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

T. OSABE et al

Serial No. 09/944,073

Group Art Unit: 2826

Filed: September 4, 2001

Examiner: T. Tran

For: A SEMICONDUCTOR NON-VOLATILE MEMORY (As Amended)

**SUPPLEMENTAL AMENDMENT**

Commissioner for Patents  
Washington, D.C. 20231

Sir:

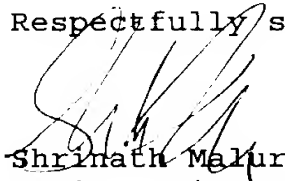
Further to the Amendment filed February 25, 2003, please  
amend the above-identified application as follows.

**REMARKS**

Approval is hereby requested for a proposed drawing  
correction to Figure 2 to modify the lead line for reference  
numeral J10. No new matter has been added. A separate letter  
to the Official Draftsperson is enclosed.

Reconsideration and reexamination are respectfully  
requested.

Respectfully submitted,

  
Shrinath Malur  
Registration No. 34,663  
Attorney for Applicants

MATTINGLY, STANGER & MALUR  
1800 Diagonal Rd., Suite 370  
Alexandria, Virginia 22314  
(703) 684-1120  
Date: March 6, 2003

RECEIVED  
MAR - 7 2003  
TECHNOLOGY CENTER 2800